# High Efficiency Low Noise Large Volume Receiver Stereo TLTR-AGC 3<sup>rd</sup> Generation Smart K Audio Amplifier With FM Mode

### **FEATURES**

- Triple-Level Triple-Rate AGC algorithm to effectively eliminate noise, pure sound quality
- Innovation high efficient, large drive high voltage 2X DO- Chargepump, efficiency up to 90%
- Highest voltage: 8.5V
- Hardware compatible with AW87319CSR
- Low noise:
  - 9 μV (Class AB Receiver THD+N=0.4%)
  - 16 μV (Class D Receiver THD+N=0.02%)
  - 38 µV (Class K Speaker THD+N=0.02%)
  - 38 µV (FM Mode Class AB Speaker THD+N=0.28%)
- Support high power receiver stereo application
- Selectable speaker-guard power level: 0.5W~1.5W@8ohm, 100mW/step
- Selectable receiver-guard power level: 0.1W~1.5W@8ohm,100mW/step 0.025W~0.375W@32ohm, 25mW/step
- Output Power: 3W@8Ω 3.5W@6Ω
- Speaker & AB/D receiver 2-in-1 mode application
- ♦ Shutdown current: 0.1µA
- Super TDD-Noise suppression
- Excellent pop-click suppression
- Support 1.8V logic I<sup>2</sup>C control
- High PSRR: -95dB (217Hz)
- Small 2.545mm\*2.075mm CSP-18B package

### **APPLICATIONS**

Smart phone \ Tablet PC

### DESCRIPTION

AW87349 is specifically designed to improve the musical output dynamic range, enhance overall sound quality. It is a new high efficiency, low noise, constant large volume, 3rd generation Smart K audio amplifier. AW87349 integrates AWINIC's proprietary Triple-Level Triple-Rate AGC audio algorithm, effectively eliminating music noise and improving sound quality and volume. AW87349 integrated high voltage DO-Chargepump technology with efficiency up to 90%, significantly improving the dynamic range of the music output. AW87349 noise floor is as low as to 38µV at speaker mode, with 102dB high signal-to-noise-ratio(SNR). The ultra-low distortion 0.02% and unique Triple-Level Triple-Rate AGC technology bring high quality music enjoyment.

AW87349 supports speaker(SPK) and high power receiver (RCV) stereo applications, supports speaker and receiver 2-in-1 applications, class AB/D receiver optional. Class AB receiver has 9µV ultra-low noise and -95dB high PSRR performance to completely suppress TDD-noise.

AW87349 controls internal registers through the I<sup>2</sup>C interface. Register parameters include chargepump output voltage, power amplifier gain, Triple-Level Triple-Rate AGC parameters, etc.

AW87349 built-in over current protection, over temperature protection and short circuit protection function, effectively protect the chip. AW87349 features small 2.545mm\*2.075mm CSP-18B package.

### TYPICAL APPLICATION CIRCUIT

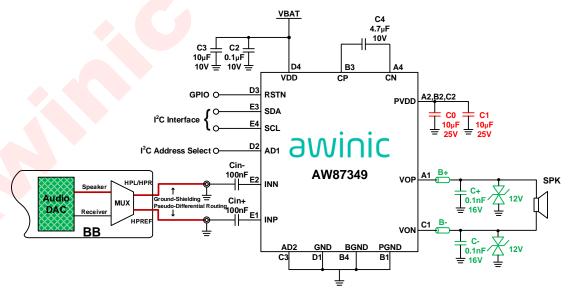


Figure 1 AW87349 Single-ended Input Mode Application Diagram

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### PIN CONFIGURATION AND TOP MARK

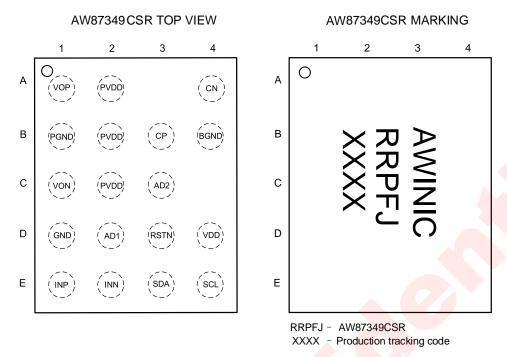


Figure 2 AW87349 Pin Diagram Top View and Device Marking

### **PIN DEFINITION**

Number	Symbol	Description
A1	VOP	Positive audio output terminal
A2,B2,C2	PVDD	Cha <mark>rge</mark> pump output voltage
A4	CN	Negative input chargepump flying capacitor
B1	PGND	Amplifier power ground
В3	СР	Positive input chargepump flying capacitor
B4	BGND	Chargepump power ground
C1	VON	Negative audio output terminal
C3	AD2	I <sup>2</sup> C address pin2
D1	GND	Ground
D2	AD1	I <sup>2</sup> C address pin1
D3	RSTN	Reset pin, active low reset, the internal 300KΩ pull-down resistor in chip
D4	VDD	Power supply
E1	INP	Positive audio input terminal
E2	INN	Negative audio input terminal
E3	SDA	I <sup>2</sup> C-bus data input/output
E4	SCL	I <sup>2</sup> C-bus clock input

### **AWINIC CLASS K FAMILY**

OPERATION MODE	AW87329CSR	AW87339CSR	AW87349CSR
CLASS K Speaker Mode	4	4	√
CLASS AB/D 2-in-1 Receiver Mode	√	4	√
High Power Receiver Stereo Mode		4	√
CLASS AB FM Mode			<b>√</b>

### **FUNCTIONAL DIAGRAM**

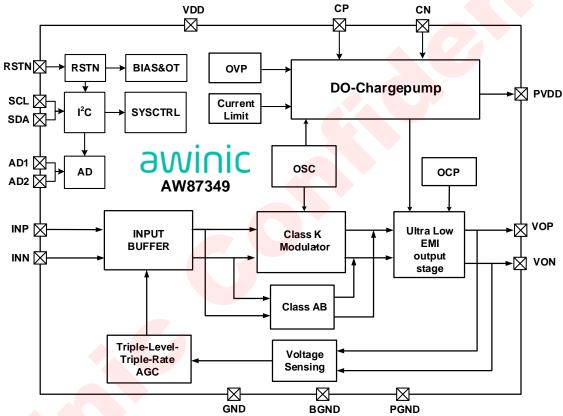


Figure 3 AW87349 Functional Diagram

### TYPICAL APPLICATION CIRCUIT

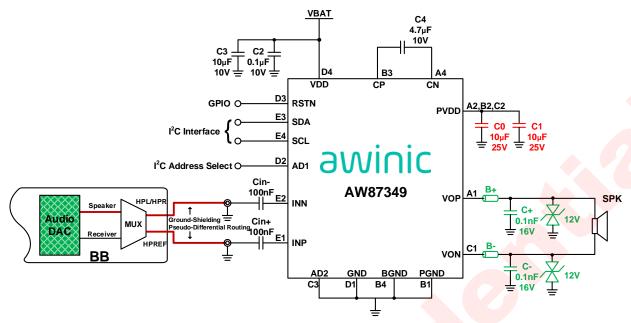


Figure 4 AW87349 Single-ended Input Mode Application Diagram (Note 1)

**Note1:** When single-ended input, audio signal line from audio DAC (HPL or HPR) can arbitrarily connected to either of INN or INP input terminal. The other terminal must be connected to reference ground (HPREF) through input capacitor and resistor.

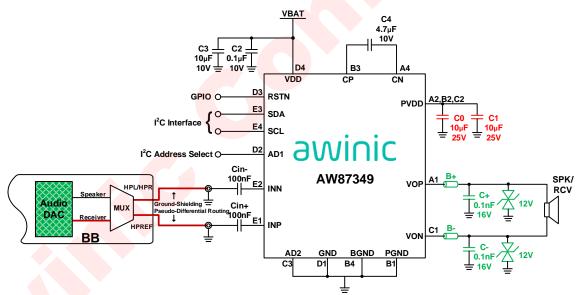


Figure 5 AW87349 Speaker & Receiver 2-in-1 Mode Application Diagram

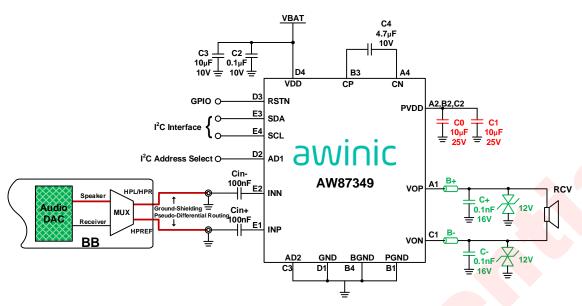
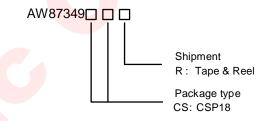


Figure 6 AW87349 High Power Receiver Stereo Mode Application

### **ORDERING INFORMATION**

Product Type	Operation temperature range	Package	Device Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW87349CSR	-40°C∼85°C	CSP-18B	RRPFJ	MSL1	ROHS+HF	Tape and Reel 6000 pcs



## ABSOLUTE MAXIMUM RATING (Note2)

Parameter	Range		
Supply Voltage V <sub>DD</sub>	-0.3V to 6V		
Chargepump output voltage PVDD	-0.3V to 9.5V		
VOP,VON	-0.3V to PVDD+0.3V		
СР	-0.3V to PVDD+0.3V		
CN	-0.3V to VDD+0.3V		
INN,INP	-0.3V to VDD+0.3V		
Minimum load resistance R <sub>L</sub>	5Ω		
Package Thermal Resistance θ <sub>JA</sub>	60°C/W		
Ambient Temperature Range	-40°C to 85°C		
Maximum Junction Temperature T <sub>JMAX</sub>	165°C		
Storage Temperature Range T <sub>STG</sub>	-65°C to 150°C		
Lead Temperature (Soldering 10 Seconds)	260°C		
ESD Rating (Note 3)			
HBM(human body model)	±2kV		
MM (machine model)	±400V		
CDM(charged-device model)	±2kV		
Latch-up	1		
Test Condition IEDEC STANDARD NO 70F SERTEMBER 2040	+IT: 450mA		
Test Condition: JEDEC STANDARD NO.78E SEPTEMBER 2016	-IT: -450mA		

**Note 2:** Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

**Note 3:** The human body model is a 100pF capacitor discharged through a 1.5k $\Omega$  resistor into each pin. Test method: MIL-STD-883J Method 3015.9

Test method of the char<mark>ge device model: JEDEC EIA/JESD22-C101F</mark>

Test method of the machine model: JEDEC EIA/JESD22-A115

### **ELECTRICAL CHARACTERISTICS**

 $Test\ condition:\ T_A=25^{\circ}C,\ VDD=3.6V,\ PVDD\ OVP=8V,\quad R_L=8\Omega+33\mu H,\ f=1kHz\ \ (unless\ otherwise\ noted)$ 

	Parameter	Test cond	ditions	Min	Тур	Max	Units
$V_{DD}$	Power supply voltage			2.8		5.5	V
	Under-voltage protection voltage			2.5		٧	
UVLO	Under-voltage protection hysteresis voltage			100		mV	
V <sub>IH</sub>	RSTN, SCL, SDA, AD1, AD2 high-level input voltage			1.3		V <sub>DD</sub>	V
$V_{IL}$	RSTN, SCL, SDA, AD1, AD2 low-level input voltage			0		0.45	V
I <sub>SD</sub>	Shutdown current	V <sub>DD</sub> =3.6V, RSTN=0V			0.1	1	μA
$T_TG$	Thermal AGC start temperature threshold				150		$^{\circ}\!$
$T_{TGR}$	Thermal AGC exit temperature threshold				130		$^{\circ}$ C
$T_{SD}$	Over temperature protection threshold				160		°C
$T_{SDR}$	Over temperature protection recovery threshold				130		°C
$T_ON$	Turn-On time			40		ms	
DO-Char	gepump						
PVDD	The maximum Output voltage	V <sub>DD</sub> =2.8V to 4V, PVD		2*VDD		V	
1 400	The maximum output voltage	V <sub>DD</sub> >4V			8 (Note4)		V
OVP	OVP voltage	V <sub>DD</sub> >4V		8 (Note4)		V	
0 0 1	OVP hysteresis voltage	V <sub>DD</sub> >4V			50		mV
F <sub>CP</sub>	Chargepump operating frequency	V <sub>DD</sub> =2.8V to 5.5V		1.2	1.6	2.0	MHz
$\eta_{CP}$	Chargepump efficiency	V <sub>DD</sub> =4.2V, I <sub>load</sub> =200m/	4		90		%
$T_{ST}$	Softstart Time	No load, COUT=4.7µl	F		2		ms
I <sub>SHORT</sub>	Current limit when PVDD short to ground				300		mA
Class K	MODE						
Vos	Output offset voltage	No input		-30	0	30	mV
η	total efficiency (CP+Class D)	V <sub>DD</sub> =4.2V, Po=2.5W, PVDD OVP=8.5V	R <sub>L</sub> =8Ω+33μH,		80		%
Iq	Speaker Quiescent current	$V_{DD}$ =3.6V, input ac graph R <sub>L</sub> =8 $\Omega$ +33 $\mu$ H	ounded,		14		mA
Vinp	Recommended input signal amplitude	V <sub>DD</sub> =2.8V to 5.5V				1	Vp
Fosc	Modulation frequency	V <sub>DD</sub> =2.8V to 5.5V		600	800	1000	kHz
Dogo	TITE ACC power	R <sub>L</sub> =8Ω+33μΗ		0.72	0.8 (Note4)	0.88	W
Pagc	TLTR AGC power	$R_L=6\Omega+33\mu H$		0.96	1.067 <sup>(Note4)</sup>	1.17	W
PSRR	Power supply rejection ratio	V <sub>DD</sub> =4.2V,	217Hz		-75		dB
rokk	i ower supply rejection fallo	Vpp_sin=200mV	1kHz		-72		dB
SNR	Signal-to-noise ratio	V <sub>DD</sub> =4.2V, PVDD OVF Av=8V/V , THD+N=19			102		dB

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	Parameter	Test	conditions	Min	Тур	Max	Units
SNR	Signal-to-noise ratio	V <sub>DD</sub> =4.2V, PVD Po=0.8W, Av=8	D OVP=8.5V, V/V, R <sub>L</sub> =8Ω+33μH		94		dB
E <sub>N</sub>	Speaker Output noise	Av=16 V/V Av=8 V/V	20Hz to 20kHz, input ac grounded, A-weighting		48		μV
Av	Speaker gain	V <sub>DD</sub> =2.8V to 5.5			24 <sup>(Note4)</sup>		dB
	Speaker Inner input resistance	Av=16 V/V			9		
Rini	Speaker Inner input resistance	Av=8 V/V			18		kΩ
	Speaker input Cut-off frequency	Cin=68nF, Av=	16 V/V		260		9,
	Speaker input Cut-off frequency	Cin=68nF, Av=8	3 V/V		130		
Fin	Speaker input Cut-off frequency	Cin=100nF, Av	=16 V/V		177		Hz
	Speaker input Cut-off frequency	Cin=100nF, Av	=8 V/V		88.5		
THD+N	Total harmonic distortion + noise	V <sub>DD</sub> =4.2V, Po=0 R <sub>L</sub> =8Ω+33μH, fs OVP=8.5V			0.02		%
		THD+N=1%, Ru PVDD OVP=8.5	=8Ω+33μH, V <sub>DD</sub> =4.2V, 5V		3.01		W
Po	Speaker Output Power	THD+N=10%, F V <sub>DD</sub> =4.2V, PVD		3.64		W	
10	opeanor output i ower	THD+N=1%, RL=6Ω+33μH, VDD=4.2V, PVDD OVP=8.5V			3.51		W
		THD+N=10%, F VDD=4.2V, PVD			4.26		W
FM MOD	E(CLASS AB, 1X Chargepump)						
Iq	Quiescent current	$V_{DD}$ =3.6V, input $R_L$ =8 $\Omega$ +33 $\mu$ H	ac grounded,		8.0		mA
η	Efficiency	V <sub>DD</sub> =4.2V,Po=0	.8W, R <sub>L</sub> =8Ω+33μΗ		67		%
Av	Speaker gain	V <sub>DD</sub> =2.8V to 5.5	V		24 (Note4)		dB
	Speaker Inner input resistance	Av=16 V/V			9		
Rini	Speaker Inner input resistance	Av=8 V/V			18		kΩ
	Speaker input Cut-off frequency	Cin=100nF, Av	=16 V/V		177		
Fin	Speaker input Cut-off frequency	Cin=100nF, Av	=8 V/V		88.5		Hz
Pagc	TLTR AGC power	R <sub>L</sub> =8Ω+33μH		0.72	0.8 (Note4)	0.88	W
		V <sub>DD</sub> =4.2V,	217Hz		-69		dB
PSRR	Power supply rejection ratio	Vpp_sin=200m	/ 1kHz		-68		dB
SNR	Signal-to-noise ratio	V <sub>DD</sub> =4.2V, PVD Av=8V/V, R <sub>L</sub> =89	D=VDD, Po=0.8W, Ω+33μΗ		94		dB
_	Canadian Outsut asias	Av=16 V/V	20Hz to 20kHz, input		48		
E <sub>N</sub>	Speaker Output noise	Av=8 V/V	ac grounded, A-weighting		38		μV
THD+N	Total harmonic distortion + noise	V <sub>DD</sub> =4.2V, Po=0 R <sub>L</sub> =8Ω+33μH, fs OVP=8.5V			0.28		%
		THD+N=1%, R <sub>L</sub> =8Ω+33μH, V <sub>DD</sub> =4.2V, PVDD=VDD			0.95		W
Ро	Speaker Output Power	THD+N=10%, F VDD=4.2V, PVD	Rι=8Ω+33μH, D=VDD		1.20		W
2-in-1 Re	ceiver MODE(CLASS AB/D, 1X Char	gepump)					
Iq	D Receiver quiescent current (overall)	$V_{DD}$ =3.6V, input $R_L$ =8 $\Omega$ +33 $\mu$ H	ac grounded,		5.8		mA

	Parameter	Test c	onditions	Min	Тур	Max	Units
	AB Receiver quiescent current (overall)	$V_{DD}$ =3.6V, input a R <sub>L</sub> =8Ω+33μH	c grounded,		6.5		mA
	D Receiver efficiency	V <sub>DD</sub> =4.2V,Po=0.8	W, R <sub>L</sub> =8Ω+33μΗ		87		%
η	AB Receiver efficiency	V <sub>DD</sub> =4.2V,Po=0.8	W, R <sub>L</sub> =8Ω+33μH		67		%
Av	gain	V <sub>DD</sub> =2.8V to 5.5V			O (Note4)		dB
	D Receiver Inner input resistance	Av=1 V/V Av=1 V/V			96		kΩ
Rini	AB Receiver Inner input resistance				48		kΩ
	D Receiver input cut-off frequency	Cin=100nF, Av=1	V/V		16.5		Hz
Fin	AB Receiver input cut-off frequency	Cin=100nF, Av=1	V/V		33		Hz
	D Receiver output noise	Av=1V/V		16		μV	
E <sub>N</sub>	AB Receiver output noise	ac grounded, A-weighting			9		μV
THD+N	Total harmonic distortion + noise	V <sub>DD</sub> =4.2V, Po=0.1W,R <sub>L</sub> =8Ω+33μH, f=1kHz, D Receiver			0.02		%
THEFIN	Total Harmonic distortion + noise	V <sub>DD</sub> =4.2V, Po=0.7 f=1kHz, AB Rece			0.4		%
	D Receiver Power supply rejection	V <sub>DD</sub> =4.2V,	217Hz		-78		dB
PSRR	ratio	Vp-p_sin=200mV	1kHz		-76		dB
1 SIXIX	AB Receiver Power supply	V <sub>DD</sub> =4.2V,	217Hz		-100		dB
	rejection ratio	Vp-p_sin=200mV	1kHz		-100		dB
	D Receiver Output Power	THD+N=1%, RL=	8Ω+33μH, Vdd=4.2V		0.95		W
Do	Directive Output Fower	THD+N=10%, Ru	= <mark>8Ω+</mark> 33μH, Vdd=4.2V		1.19		W
Po	AD Deceives Outsit Device	THD+N=1%, RL=	8 <mark>Ω+3</mark> 3μH, Vdd=4.2V		0.875		W
	AB Receiver Output Power	THD+N=10%, RL	=8Ω+33μH, Vdd=4.2V		1.15		W
Triple-Le	vel Triple-Rate AGC						
T <sub>AT1</sub>	AGC1 Attack Time				0.08 (Note4)		ms/dB
T <sub>AT2</sub>	AGC2 Attack Time				0.64 (Note4)		ms/dB
T <sub>AT3</sub>	AGC3 Attack Time				41 <sup>(Note4)</sup>		ms/dB
$T_RLT$	Release time				21 <sup>(Note4)</sup>		ms/dB
	Th	V <sub>DD</sub> =2.8V to 5.5V		-13.5		dB	
A <sub>MAX</sub>	The maximum attenuation gain	V <sub>DD</sub> =2.8V to 5.5V	, RCV_LOAD=1		-10.5		dB

Note 4: Registers are adjustable; Refer to the list of registers.

### **MEASUREMENT SETUP**

AW87349 features switching digital output, as shown in Figure 7. Need to connect a low pass filter to VOP/VON output respectively to filter out switch modulation frequency, then measure the differential output of filter to obtain analog output signal.

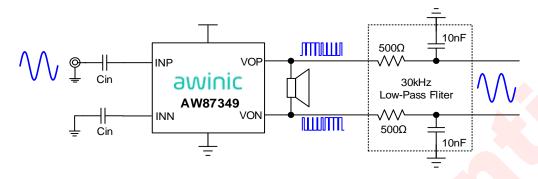


Figure 7 AW87349 Test Setup

Low pass filter uses resistance and capacitor values listed in Table 1.

R <sub>filter</sub>	$C_{filter}$	Low-pass cutoff frequency
500Ω	10nF	32kHz
1kΩ	4.7nF	34kHz

Table 1 AW87349 Recommended Values for Low Pass Filter

### **Output Power Calculation**

According to the above test methods, the differential analog output signal is obtained at the output of the low pass filter. The valid values Vo\_rms of the differential signal, as shown in Figure 8:

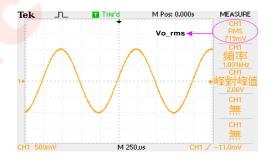
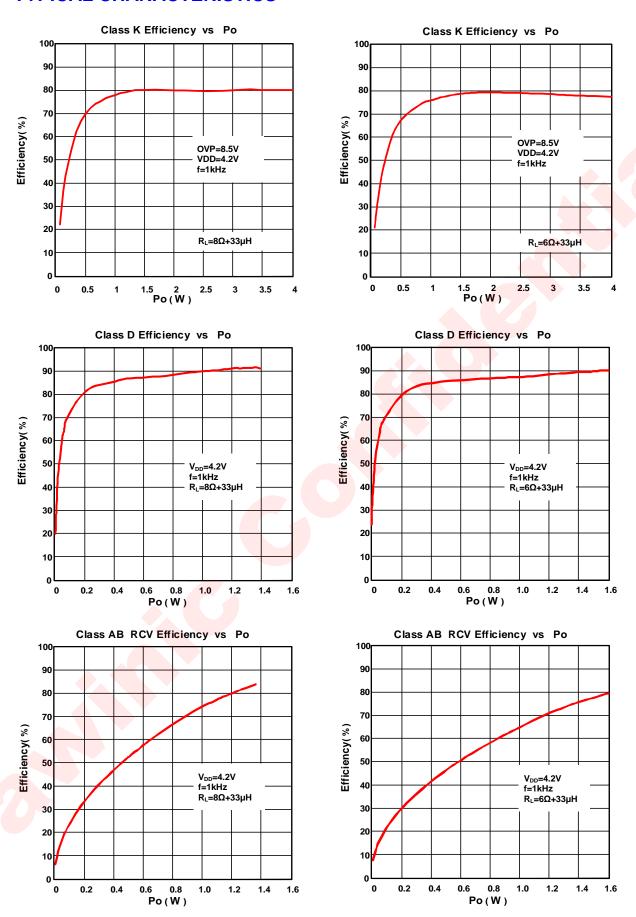


Figure 8 Output RMS Value

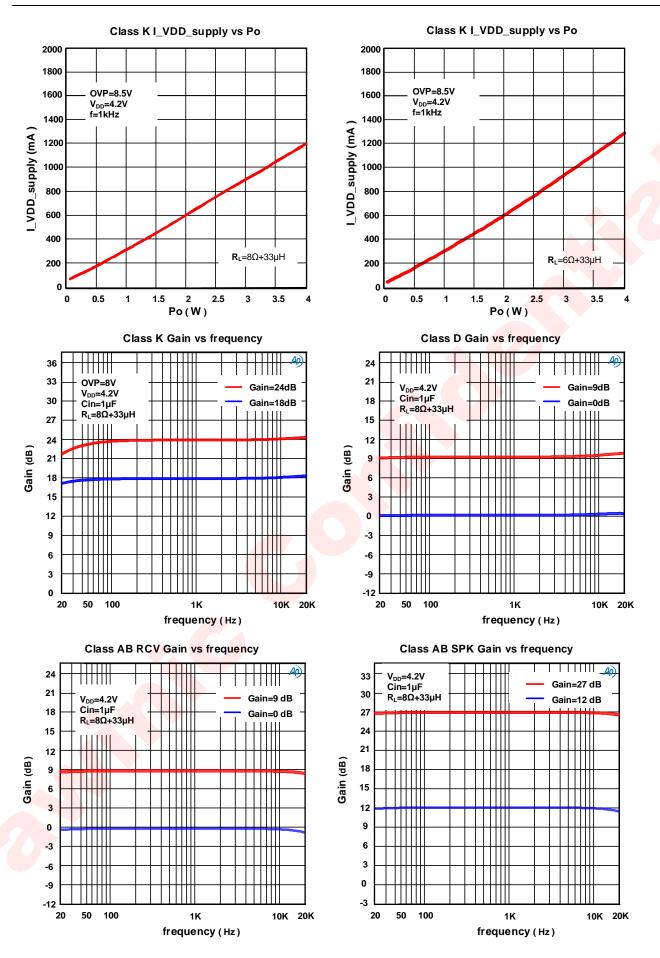
The power calculation of Speaker is as follows:

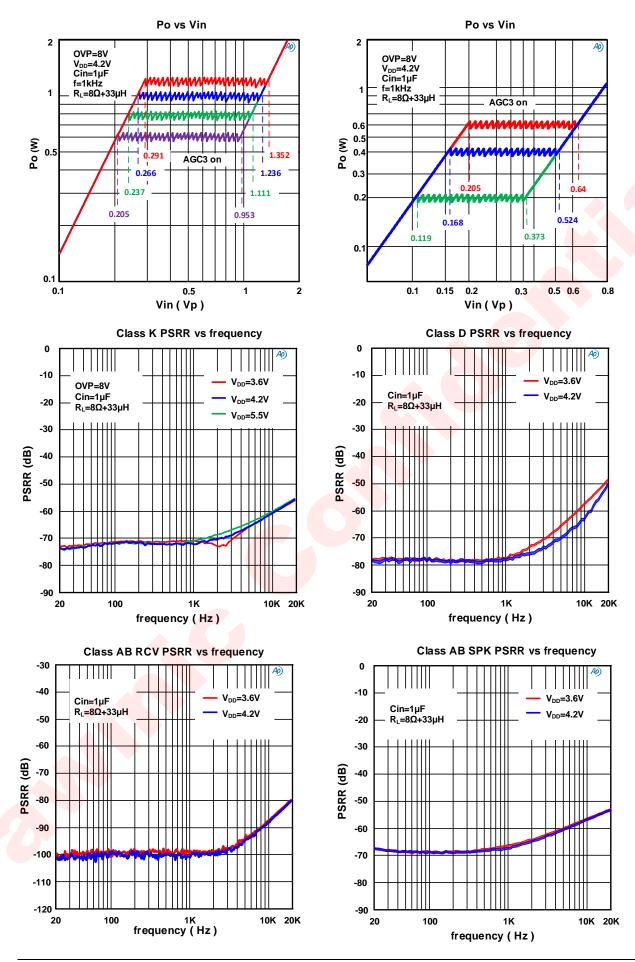
$$P_L = \frac{(V_{O_ms})^2}{R_L}$$
  $R_L$ : load impedance of the speaker

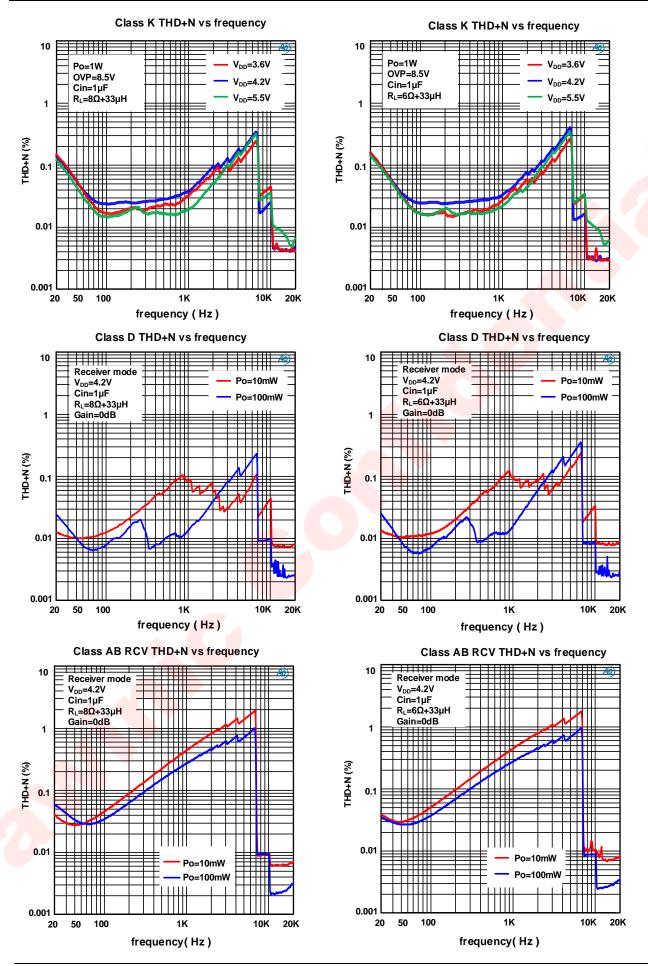
### TYPICAL CHARACTERISTICS

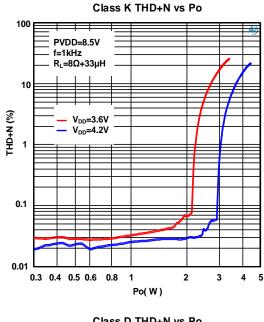


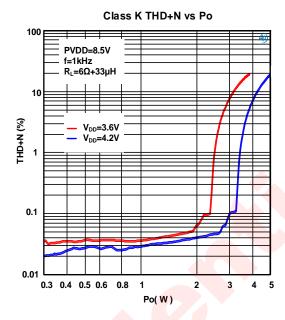
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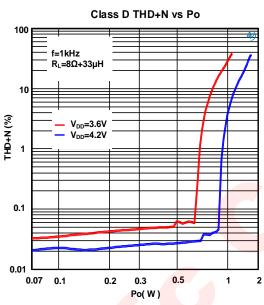


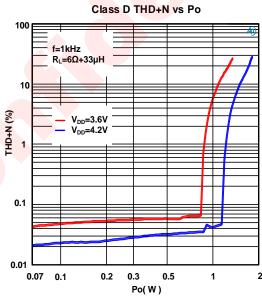


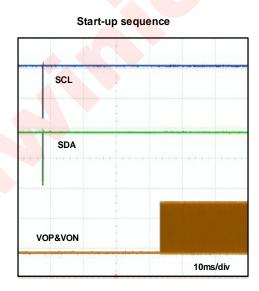


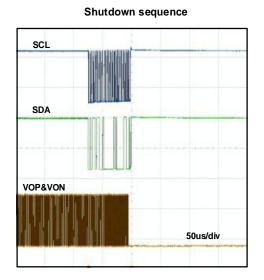




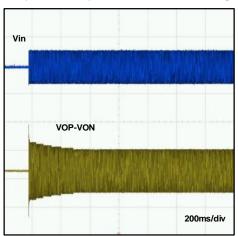




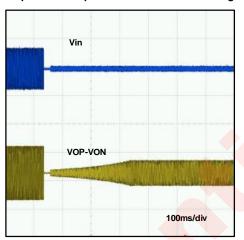




Triple-Level Triple-Rate AGC Attack Timing



Triple-Level Triple-Rate AGC Release Timing



### **WORKING PRINCIPLE**

AW87349 is specifically designed to improve the musical output dynamic range, enhance the overall sound quality, which is a new high efficiency, low noise, constant large volume, 3rd generation Smart K audio amplifiers. AW87349 integrates AWINIC's proprietary Triple-Level Triple-Rate AGC audio algorithm, effectively eliminating music noise and improving sound quality and volume. AW87349 integrated efficiency up to 90% of High voltage DO-Chargepump technology, significantly improving the dynamic range of the music output.AW87349 noise floor is as low as to  $38\mu V$ , with 102dB high signal-to-noise-ratio (SNR). The ultra-low distortion 0.02% and unique Triple-Level Triple-Rate AGC technology bring high quality music enjoyment.

AW87349 supports speaker and high power receiver stereo applications, supports speaker and receiver 2-in-1 applications, AB/D Receiver optional, ultra-low noise is 9µV.

AW87349 supports FM Mode by using Class AB power amplifier. It makes no interference from output signal for FM Application. Under FM Mode, AW87349 has multiple selectable speaker-guard output power level from 0.5W to 1.5W.

AW87349 controls internal registers through the I<sup>2</sup>C interface. Register parameters include chargepump output voltage, power amplifier gain, Triple-Level Triple-Rate AGC parameters etc.

AW87349 built-in over current protection, over temperature protection and short circuit protection function, effectively protect the chip. AW87349 features small 2.545mm\*2.075mm CSP-18B package.

### **CONSTANT OUTPUT POWER**

In the mobile phone audio applications, the AGC function to promote music volume and quality is very attractive, but as the lithium battery voltage drops, general power amplifier output power will reduce gradually. So, it is hard to provide high quality music within the battery voltage range. AW87349 uses unique Triple-Level Triple-Rate technology, within lithium battery voltage range (3.3V~4.35V), to guarantee that output power is constant, and the output power will not drop along with the decrease of lithium battery voltage. In the process of using the phone, even if the battery voltage drops, AW87349 can still provide high quality large volume music enjoyment. The output power of AW87349 can be configured from 0.5W to 1.5W via I<sup>2</sup>C, matching general speakers. Unique Triple-Level Triple-Rate AGC technology can bring high-quality music enjoyment.

### Triple-Level Triple-Rate AGC technology

AWINIC proprietary Triple-Level Triple-Rate AGC technology is designed for the protection of the high voltage power amplifier, which is divided into AGC1, AGC2 and AGC3 power levels, to obtain a large volume while maintaining excellent sound quality.

In practical applications, speaker can continuously work long hours at rated power, and also can work short-term at high power. For example, in the standard reliability of the loudspeaker experiment, the powder of peak power reached around four times of the rated power. For achieving larger volume and better sound quality, speakers need to work at high power for short periods of time, in order to improve the performance of the speaker. AW87349 Triple-Level Triple-Rate AGC technology can fit the speaker better and perform better overall performance. AGC1 prevents output signal clipping by detecting output voltage in a very short time after clipping, which can effectively restrain the noise clipping; AGC2 can improve the dynamic range of the music in a relatively short period of time; AGC3 can make the speaker work under rated power, which can effectively improve the volume and protect the speaker. Triple-Level Triple-Rate AGC can obtain more excellent overall performance.

Triple-Level Triple-Rate AGC detects the peak output voltage of the power amplifier, when the output peak voltage is higher than the compression threshold voltage, the amplifier gain decreases in 0.5dB step. When the output peak voltage is lower than the release threshold voltage, the amplifier gain is recovery to the initial gain in 0.5dB step. The detailed process can be described as follows:

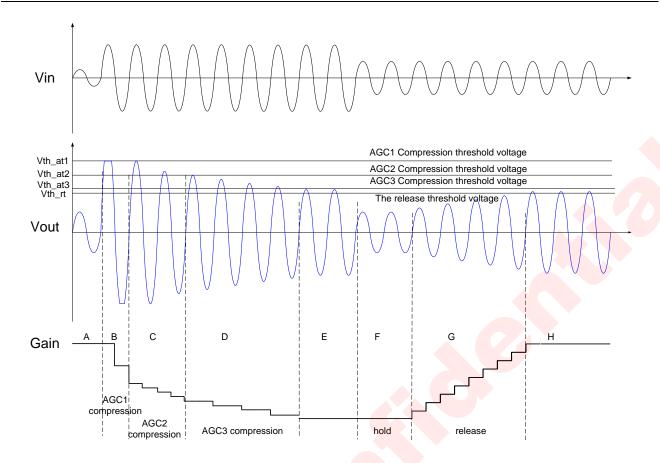


Figure 9 Triple-Level Triple-Rate AGC Operation Principle

A: Small input signal, the output voltage is lower than threshold voltage Vth of AGC, AGC don't work.

B: Input voltage becomes large. It leads to the output voltage clipping, AGC1 starts fast compression, the attack time is set through the I<sup>2</sup>C register 0x0Ah [3:2], when the output voltage is higher than Vth\_at1, and gain register began to decrease. Gain decreases when the output signal passes through the zero. It eliminates the clipping noise as soon as possible.

C: When the output voltage is not clipping and higher than threshold voltage Vth\_at2, AGC2 starts work, the attack time is set through the I<sup>2</sup>C register 0x09h [4:2], gain register begins to decrease at a certain rate. Gain register began to decrease. Gain decreases when the output signal passes through the zero. The output voltage gradually decreases to below the AGC2 attack threshold voltage Vth\_at2, which can protect the speaker and enhance the sound.

D: When the output voltage is lower than the AGC2 attack threshold voltage Vth\_at2 and higher than the AGC3 attack threshold voltage Vth\_at3, AGC3 starts work, the attack time is set through the I<sup>2</sup>C register 0x07h [4:2], and gain register began to decrease at a certain rate. Gain decreases when the output signal passes through the zero, so the output voltage gradually decreases to below of the AGC3 attack threshold voltage Vth\_at3, matching the speaker to achieve greater volume and better sound quality.

E: Triple-Level Triple-Rate AGC attack time ends, Amplifier output power is close to the speaker rated power. F: Input voltage decreases, the output voltage becomes lower than the release threshold voltage Vth\_rt, at this point, gain remains the same in the maintain time (10ms~20ms).

G: Gain increases when the time of output voltage lower than the release threshold voltage Vth\_rt is longer than the holding time. The release time can be set through I<sup>2</sup>C register 0x07h [7:5].

H: Stop release when the output signal is larger than the release threshold or the gain is equal to the initial value. The output voltage remains constant.

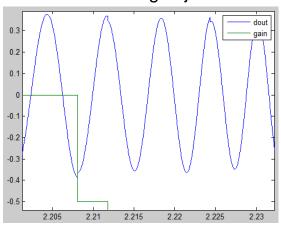
Triple-Level Triple-Rate AGC can switch independently according to different application requirements. Such as close AGC1 and AGC2, retain only AGC3, this is the single-AGC mode, similar to AW8736 (AGC3 attack

time is set to 1.28ms/dB; release time is set to 41ms/dB); Close AGC2, open AGC1 and AGC3, this is Multi\_level AGC. It can be set similar to AW8738 (AGC1 attack time is set to 80us/dB; AGC3 attack time is set to 0.64ms/dB; release time is set to 10.24ms/dB).

### **Zero-Crossing Adjustment Technology**

Traditional AGC doesn't contain zero adjustment technology; AGC gain changes generally at the peak, the gain variation at the peak would generate a certain transient distortion, such distortions are audibly imperceptible. Such as individual songs have a slight click.

### no zero-crossing adjustment



### zero-crossing adjustment

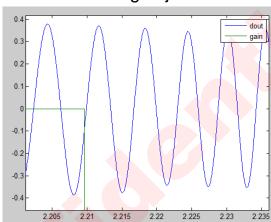


Figure 10 Zero-adjust Comparison

As shown above, when there is no zero-adjustment technology, it can be seen the obvious step change at the peak of large signal, the steps sound slightly perceived in special audio. Gain changes at zero. The steps disappear by using zero-crossing detection technology. Using zero detection technology can make the music pure and natural.

### **DO-Chargepump**

AW87349 features DO-chargepump technology, with high efficiency and high drive capability, operating frequency 1.6MHz, built-in soft start circuit, current limiting control loop and over-voltage control loop to ensure circuit stable and reliable work.

### High efficiency

AW87349 features DO-chargepump architecture, the output voltage PVDD is twice of the input voltage VDD, ideal efficiency up to 100%. The efficiency of the DO-chargepump is the ratio of the output power to input power:

$$\eta = \frac{P_{OUT}}{P_{IN}} * 100\%$$

For example, in an ideal M times the DO-chargepump, the input current  $I_{IN}$  is M times of  $I_{OUT}$ , the efficiency formula is:

$$\eta = \frac{P_{OUT}}{P_{IN}} * 100\% = \frac{V_{OUT} * I_{OUT}}{V_{IN} * M * I_{OUT}} * 100\% = \frac{V_{OUT}}{M * V_{IN}} * 100\%$$

Where M is the operating mode variable of the chargepump,  $V_{IN}$  is the output voltage of chargepump,  $I_{OUT}$  is the load current. For the DO-chargepump, the output voltage is twice of the input voltage, can greatly improve the power efficiency, taking into account the chargepump internal switching losses and IC quiescent current loss, the actual efficiency is as high as 90%.

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AW87349 DO-chargepump can be set to pass-through mode and 2X chargepump mode via the register 0x01h [2] to supply power to the Class D output stage.

### Chargepump structure

The basic diagram of the chargepump shows in Figure 11, the chargepump in AW87349 has four switches, the output voltage PVDD can reach twice of the input voltage through the four switches of the timing control.

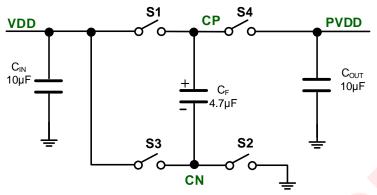


Figure 11 Chargepump Schematic Diagram

The chargepump works with two phases, in  $\Phi$ 1, as shown in the Figure 12: S1, S2 on, VDD charges the capacitor  $C_F$ .

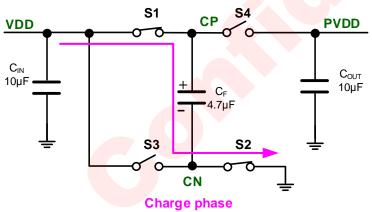


Figure 12 Φ1: Flying Capacitor Charging

In  $\Phi$ 2, as shown in the Figure 13: S1 and S2 off, S3 and S4 on, since the voltage across the capacitor cannot be changed abruptly, the capacitors  $C_F$  are superimposed on VDD, causing the PVDD to rise to a higher voltage.

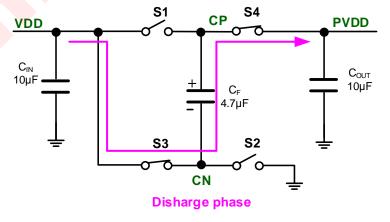


Figure 13 Φ2: Flying Capacitor Charge is Transferred to C<sub>OUT</sub>



### Soft start

In order to limit the inrush current of the power supply during the start of the chargepump, the chargepump has a soft start function. The current limit is 300mA during start-up. Soft start time is 2ms.

### **Current limiting control**

DO-chargepump architecture integrates the current limiting control loop, in normal operation, the current limiting control loop controls the maximum output current capability of the chargepump when the load is too heavy or the chargepump flows through a large current.

### Over-voltage protection(OVP) control

The output voltage PVDD is twice of the input voltage VDD in DO-chargepump structure, providing high voltage rail for internal power amplifier circuits, allowing the amplifier in the lithium battery voltage range to provide greater output dynamic range, in order to achieve high volume, high-quality class K audio amplifier playback sound quality. DO-chargepump integrated over-voltage protection control loop, when the input voltage VDD is greater than 4V, the output voltage PVDD is not twice of VDD, it is determined by the over-voltage control loop. And PVDD is stable at 8.0V.

### Speaker & Receiver 2-in-1 application

AW87349 built-in speaker and receiver 2-in-1 application mode, through the register settings, there are class AB-type 2-in-1 receiver mode and class D-type 2-in-1 receiver mode can be selected, the gain can be adjusted through the  $I^2C$  register 0x05, adjustable range of 0~10.5dB, the application is very flexible. The 2-in-1 receiver mode uses the signal path of the speaker, with ultra-low distortion and strong drive capability, and eliminates the need for additional peripheral components, saving system cost and PCB layout space. In the typical application case of Figure 5, the input capacitance Cin = 100nF, the gain is 16V/V in the speaker application mode, the input high-pass cutoff frequency is 177Hz; In 1V/V gain class D-type 2-in-1 receiver application mode, the output noise is  $16\mu V$ , the input high-pass cut-off frequency is 16.5Hz; In 1V/V gain class AB-type 2-in-1 receiver application mode, the output noise is as low as  $9\mu V$ , the input high-pass cut-off frequency is 33Hz, which is very suitable for high-definition voice applications. AW87349 can achieve speaker and receiver's 2-in-1 application without changing any hardware in the case.

### High Power Receiver Stereo Applications

AW87349 built-in high-power receiver stereo application mode, makes full use of the receiver, not only takes the voice calls into account and uses the receiver as speaker, but also combines the AWINIC's propriety TLTR-AGC technology, significantly enhancing the stereo sound quality and volume, enhancing the dynamic music, therefore, high power receiver stereo application has gradually become a mainstream application in smart phone.

AW87349 is in the high-power receiver stereo application mode, when the register 0x02h [4] is set to 1. Gain adjustable range is 0~27dB by adjusting the I<sup>2</sup>C register 0x05h [4:0], AGC3 power adjustable range is 0.1W~1.5W@8ohm receiver, 0.025W~0.375W@32ohm receiver through adjusting the I<sup>2</sup>C register 0x06h [3:0]. AW87349 can flexibly match a variety of high-power Receiver, combined with TLTR AGC technology, significantly enhance the stereo sound quality and volume, and enhance music dynamic listening.

Figure 14 AW87349 High Power Receiver Stereo Mode Application

### **RNS(RF TDD Noise Suppression)**

### **TDD Noise Causes**

GSM cell phones use TDMA (Time Division Multiple Access) slot sharing technology. The time is divided into periodic frames in TDMA, and each frame is subdivided into a plurality of time slots. In order to transmit signals to the base station, the signals sent from the base stations to the plurality of mobile terminals are arranged in a predetermined time slot in the transmission. In this case, each TDMA frame contains 8 time slots, the entire frame is about 4.615ms long, and each slot time is 0.577ms.

With GSM handset, the RF power amplifier will transmit once every 4.615ms (217Hz), and the signal will produce intermittent Burst current and strong electromagnetic radiation. Intermittent Burst current will form a power fluctuation of 217 Hz; High frequency (900MHz and 1800MHz) RF signals form a 217Hz RF envelope signal. 217Hz power fluctuations will be conducted through the conduction to the audio signal path, 217Hz RF envelope signal will be coupled through the radiation into the audio signal path, if the protection is not good, it will produce an audible TDD Noise, which includes the 217Hz noise And a harmonic noise signal of 217 Hz.

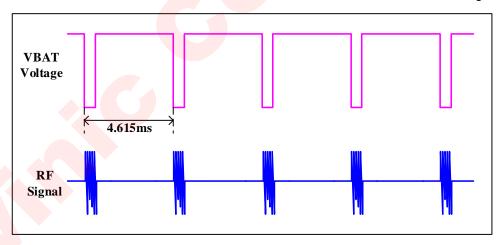


Figure 15 Schematic Diagram of Power Supply Voltage and RF Signal during GSM RF Operation

RNS fully inhibit the conduction and radiation interference by the AWINIC unique circuit architecture. Effectively improve the ability to suppress TDD Noise.

### Conduction noise suppression

When the RF power amplifier is operating, it will draw the current from the battery by 217Hz frequency, Power supply will be introduced to 217Hz power ripple since the battery has a certain internal resistance, it will be

coupled to the speaker through the audio power amplifier. The ability to suppress power fluctuations depends on the PSRR of the audio power amplifier.

$$PSRR = 20log(\frac{vout_{ac}}{vdd_{ac}})$$

Due to the input and output of the fully differential amplifier is perfectly symmetrical, theoretically, the effect of the power supply fluctuation on the two outputs is exactly the same, and the differential output is completely unaffected by the power supply fluctuation. In practice, due to process bias and other factors, the amplifier will have a certain mismatch, PSRR is generally better than -60dB, it shows the output relative to the power fluctuations can be reduced by 1000 times, such as 500mVp power fluctuations, the differential output of 0.5 MV, which basically can meet the application requirements.

But in practical applications, the power amplifier may encounter conduction of TDD Noise problem even if its PSRR is -60dB or -80dB, why is this? Because we also need to consider the impact of peripheral power mismatches of audio power amplifiers

For conventional audio power amplifiers, when the input resistor Rin and the input capacitor Cin mismatch, will greatly affect the audio power amplifier PSRR indicators, in the case of 24 times the gain, PSRR will be weakened to -46dB or so if the input resistance and Capacitor with 1% mismatch. PSRR will be weakened to -28dB or so if the input resistance and input capacitance mismatch with 10% mismatch, when the power fluctuations, it is easy to produce audible TDD Noise.

In order to enhance the audio power amplifier PSRR in the input resistance and input capacitance mismatch case, AW87349 features a unique conduction noise suppression circuit, making the power amplifier to maintain a high PSRR value even in the input resistance, the input capacitance deviation of 10% or more, this greatly inhibits the generation of conducted noise.

### Radiation noise suppression

Input traces, output traces, horn loops, and even power and ground loops are likely to be subject to RF radiation interference in the audio signal module, longer input traces and output traces similar to the antenna, especially vulnerable RF radiation effects.

The reasonable PCB layout can reduce the influence of RF radiation in the design, such as shorten the line length of input and output as much as possible; audio devices should be shielded and far away from the RF antenna, maintain the integrity of the device to audio signal pathway; to increase the small bypass capacitor RF signals in the sensitive nodes. However, in practical applications, PCB layout is difficult to fully consider the influence of RF radiation on the audio signal path, and some RF energy will still be coupled to the audio signal path to form audible TDD Noise. Therefore, AW87349 features a unique RF radiation suppression circuit, a shielding layer inside the chip, effectively prevent high frequency energy into RF chip, to ensure that the drive single of the amplifier provided to the speaker will not be affected by the antenna RF radiation, thus avoiding the antenna RF Radiation caused by TDD Noise.



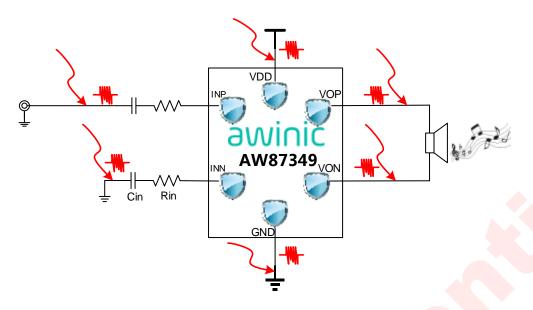


Figure 16 RF Radiation Coupling Graph

### Class D amplifier without filter

When the traditional class D amplifier is in idle state of no input signal, the output will have the inverse square wave, it will directly above the load of the speaker, will form a large current power switch on the speaker, therefore we need to increase the LC filter to restore the analog audio signal at the amplifier output. The LC filter increase the cost and PCB layout area, while increase the power consumption, reduce the performance of THD+N.

The AW87349 features a Class D amplifier without a filter, eliminating the need for an output LC filter. In the idle state of no input signal, the two outputs (VOP, VON) of the amplifier are in-phase square waves and not generate idle switching currents on the speaker load. When the input signal is added to the input terminal, the duty ratio of the output is changed. The duty cycle of the VOP becomes larger and the duty cycle of the VON becomes smaller, and the difference value of the output forms the differential amplified signal on the speaker.

### EEE

The AW87349 features a unique Enhanced Emission Elimination (EEE) technology, that controls fast transition on the output, greatly reduces EMI over the full bandwidth, fully meet FCC CLASS B specification requirements.

### **Pop-Click Suppression**

The AW87349 features unique timing control circuit, that comprehensively suppresses pop-click noise, eliminates audible transients on shutdown, wakeup, and power-up/down.

### Thermal AGC/ over temperature protection

The AW87349 features the thermal AGC patented technology, can according to the chip temperature, automatically adjust the gain of the system, reduce the power consumption of the chip, to prevent damage in case of excessive temperature.

The AW87349 has an automatic temperature detection mechanism, when the chip temperature exceeds the preset threshold of thermal AGC temperature (150°C), the chip will start the automatic gain control circuit to decrease the gain of the system, thereby reducing the energy consumption of the chip, thus slow or stop chip temperature continues to rise. When the chip temperature is restored to normal operating range (below 130°C), the automatic gain control circuit will restore the system gain to the original state. When the chip operates in a fault condition, the chip temperature is too high, up to a preset temperature protection

temperature threshold (160°C), the system starts overheating protection, the chip will be turned off, restarts to resume normal work when the chip temperature returns to normal operating range (less than 130°C).

### **Automatic recovery of overcurrent protection**

AW87349 with automatic recovery of the output overcurrent protection function, when the overcurrent occurs, AW87349 internal protection circuit will chip off to ensure that the chip is not damaged, when the short-circuit fault is eliminated, the chip will automatically resume working without restarting.



### I<sup>2</sup>C Timing feature

		Parameter	MIN	TYP	MAX	UNIT	
No.	Sym	Name	IVIIIN	111	IVIAA	ONIT	
1	f <sub>SCL</sub>	SCL Clock frequency			400	kHz	
2	t <sub>LOW</sub>	SCL Low level Duration	1.3			μs	
3	t <sub>HIGH</sub>	SCL High level Duration	0.6			μs	
4	t <sub>RISE</sub>	SCL, SDA rise time			0.3	μs	
5	t <sub>FALL</sub>	SCL, SDA fall time			0.3	μs	
6	t <sub>SU:STA</sub>	Setup time SCL to START state	0.6			μs	
7	t <sub>HD:STA</sub>	(Repeat-start) Start condition hold time	0.6			μs	
8	t <sub>SU:STO</sub>	Stop condition setup time	0.6			μs	
9	t <sub>BUF</sub>	the Bus idle time START state to STOP state	1.3			μs	
10	t <sub>SU:DAT</sub>	SDA setup time	0.1			μs	
11	t <sub>HD:DAT</sub>	SDA hold time	10			ns	

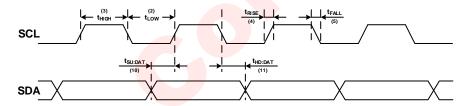


Figure 17 SCL and SDA timing relationships in the data transmission process

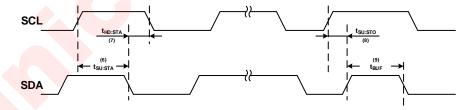


Figure 18 the Timing Relationship between START and STOP State

### General I<sup>2</sup>C Operation

The I<sup>2</sup>C bus employs two signals, SDA (data) and SCL (clock), to communicate between integrated circuits in a system. The device is addressed by a unique 7-bit address; the same device can send and receive data. In addition, Communications equipment has distinguish master from slave device: In the communication process, only the master device can initiate a transfer and terminate data and generate a corresponding clock signal. The devices using the address access during transmission can be seen as a slave device.

SDA and SCL connect to the power supply through the current source or pull-up resistor. SDA and SCL default is a high level. All data to start transmission and end of transmission requires the main device to issue

START state and STOP status:

START state: The SCL maintain a high level, SDA from high to low level STOP state: The SCL maintain a high level, SDA pulled low to high level

Start and Stop states can be only generated by the master device. In addition, if the device does not produce STOP state after the data transmission is completed, instead re-generate a START state (Repeated START, Sr), and it is believed that this bus is still in the process of data transmission. Functionally, Sr state and START state is the same. As shown in Figure 19.

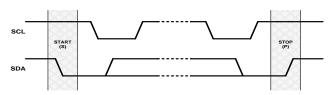


Figure 19 START and STOP State Generation Process

In the data transmission process, when the clock line SCL maintains a high level, the data line SDA must remain the same. Only when the SCL maintain a low level, the data line SDA can be changed, as shown in Figure 20. Each transmission of information on the SDA is 9 bits as a unit. The first eight bits are the data to be transmitted, and the first one is the most significant bit (Most Significant Bit, MSB), the ninth bit is an confirmation bit (Acknowledge, ACK or A), as shown in Figure 21. When the SDA transmits a low level in ninth clock pulse, it means the acknowledgment bit is 1, namely the current transmission of 8 bits data are confirmed, otherwise it means that the data transmission has not been confirmed. Any amount of data can be transferred between START and STOP state.

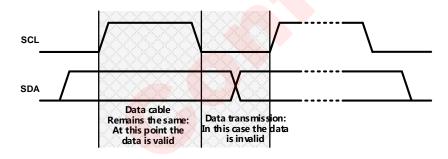


Figure 20 The Data Transfer Rules on the I<sup>2</sup>C Bus

The whole process of actual data transmission is shown in Figure 21. When generating a START condition, the master device sends an 8-bit data, including a 7-bit slave addresses (Slave Address), and followed by a "read / write" flag ( $\overline{R/W}$ ). The flag is used to specify the direction of transmission of subsequent data. The master device will produce the STOP state to end the process after the data transmission is completed. However, if the master device intends to continue data transmission, you can directly send a Repeated START state, without the need to use the STOP state to end transmission.

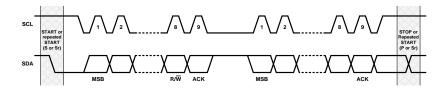


Figure 21 Data Transmission on the I<sup>2</sup>C Bus

### I<sup>2</sup>C Read/Write Processes

The following describes two kinds of ways of the I<sup>2</sup>C bus data transmission:

### **Write Process**

Writing process refers to the master device write data into the slave device. In this process, the transfer direction of the data is always unchanged from the master device to the slave device. All acknowledge bits are transferred by the slave device, in particular, AW87349 as the slave device, the transmission process in accordance with the following steps, as shown in Figure 22:

Master device generates START state. The START state is produced by pulling the data line SDA to a low level when the clock SCL signal is a high level.

Master device transmits the 7-bits device address of the slave device, followed by the "read / write" flag (flag  $R/\overline{W} = 0$ ):

The slave device asserts an acknowledgment bit (ACK) to confirm whether the device address is correct;

The master device transmits the 8-bit AW87349 register address to which the first data byte will written;

The slave device asserts an acknowledgment (ACK) bit to confirm the register address is correct;

Master sends 8 bits of data to register which needs to be written;

The slave device asserts an acknowledgment bit (ACK) to confirm whether the data is sent successfully; If the master device needs to continue transmitting data, it does not need further to send the register address for AW87349, within AW87349 each send confirmation bit(ACK) regret automatic accumulation register address then only need to repeat the sixth step and seven step:

The master device generates the STOP state to end the data transmission.

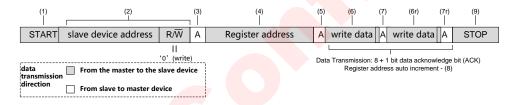


Figure 22 Writing Process (Data Transmission Direction Remains the Same)

### **Read Process**

Reading process refers to the slave device reading data back to the master device. In this process, the direction of data transmission will change. Before and after the change, the master device sends START state and slave address twice, and sends the opposite "read/write" flag. In particular, AW87349 as the slave device, the transmission process carried out by following steps listed in Figure 23:

Master device asserts a start condition;

Master device transmits the 7 bits address of AW87349, and followed by a "read / write" flag (R/W = 0);

The slave device asserts an acknowledgment bit (ACK) to confirm whether the device address is correct;

The master device sends the 8bit address that the AW87349 register needs to read the data;

The slave device asserts an acknowledgment (ACK) bit to confirm whether the register address is correct or not;

The master device restarts the data transfer process by continuously generating STOP state and START state or a separate Repeated START.

Master sends 7-bits address of the slave device and followed by a read / write flag (flag  $R/\overline{W} = 1$ ) again.

The slave device asserts an acknowledgment (ACK) bit to confirm whether the register address is correct or not.

The master transmits 8 bits of data to register which needs to be read;

The slave device sends an acknowledgment bit (ACK) to confirm whether the data is sent successfully. AW87349 automatically increment register address once after the slave sent each acknowledge bit (ACK). The master device generates the STOP state to end the data transmission.

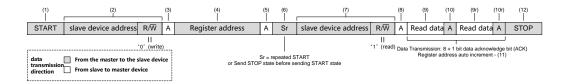


Figure 23 Reading Process (Data Transmission Direction Remains the Same)

### **Register List**

name	addr ess	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
Chip ID	0x00	0	0	1	1	1	0	0	1
SYSCTRL	0x01	0	0	0	0	EN_SW	EN_CP	EN_PA	EN_ABSPK
MODECTRL	0x02	1	0	1	RCV_LOAD(1)	RCV_MODE(2)	EN_ABRCV <sup>(3)</sup>	1	1
CPOVP	0x03	0	0	0	0	CP_OVP <sup>(4)</sup> [3]	CP_OVP <sup>(4)</sup> [2]	CP_OVP <sup>(4)</sup> [1]	CP_OVP <sup>(4)</sup> [0]
CPP	0x04	0	0	0	0	0	1	0	_1
Gain	0x05	0	0	0	Gain [4]	Gain [3]	Gain [2]	Gain [1]	Gain [0]
AGC3_Po	0x06	0	0	0	0	AGC3_Po[3]	AGC3_Po[2]	AGC3_Po[1]	AGC3_Po[0]
AGC3	0x07	AGC3_RT[2]	AGC3_RT[1]	AGC3_RT[0]	AGC3_AT[2]	AGC3_AT[1]	AGC3_AT[0]	1	0
AGC2_Po	80x0	0	0	0	0	AGC2_Po[3]	AGC2_Po[2]	AGC2_Po[1]	AGC2_Po[0]
AGC2	0x09	0	0	0	AGC2_AT[2]	AGC2_AT[1]	AGC2_AT[0]	0	0
AGC1	0x0A	1	0	0	1	AGC1_AT[1]	AGC1_AT[0]	1	PD_AGC1

- RCV\_LOAD: enable high power receiver (32ohm or 8ohm) stereo
- RCV\_MODE: enable 2-in-1 receiver application
- (3) EN\_ABRCV: enable 2-in-1 class AB receiver application
- (4) CP\_OVP: chargepump OVP voltage

register	0x00	0x01	0x02	0x03	0x04	0x05	0x06	0x07	0x08	0x09	0x0A
Default	Default 0v20 0v06 0	9   0x06   0xA3   0x06   0x05   · · · · · · · · · · · · · · · · · ·		0x00 (RCV_LOAD  RCV_MODE=1)	0,407	0,450	0,400	0,400	00		
Default	0x39	UXUb	UXA3	UXUb	UXUS	0x10 (RCV_LOAD  RCV_MODE=0)	0x07	0x52	0x06	0x08	96

### Table 2 AW87349 Register Default Value

Any register address which is more than 0x0A and all reserved bits are reserved for debugging and testing purposes. Changing their values may affect the normal function of the power amplifier; Reading them will get any possible values. AW87349's I<sup>2</sup>C address is 10110A2A1, as shown in Table 3, in order to avoid conflict with other I<sup>2</sup>C devices address, you can pull up or pull-down AW87349 of AD2 and AD1 pins to set the value of A2 and A1, respectively. The following lists specific information about all visible registers, including default values and programmable ranges.

Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
1	0	1	1	0	A2	A1	R/W

### Table 3 AW87349 Address Byte

### CHIP ID Register (address: 0x00)

I <sup>2</sup> C Bit	Name	R/W	Default	Description
7:0	IDCODE	R	0x39	Chip ID will be returned after reading. All configuration registers will be reset to default values after 0xAA is written.

### SYSTEM CONTROL (SYSCTRL) Register (address: 0x01)

I <sup>2</sup> C Bit	Name	R/W	Default	Description
7:4			0000	Reserved and Unused
				Chip Software Enable
3	EN SW	R/W	0	0: Chip Software Disable:
3	EIN_SVV	IN/VV	U	Shutdown the whole chip except PORN.
				1: Chip Software Enable
				Chargepump Enable:
2	EN CP	R/W	1	This bit must be unchanged when EN_SW=1.
2	EN_CF	17/77	Į.	0: Disable Chargepump, PVDD=VBAT
				1: Enable Chargepump
1	ENI DA	R/W	4	PA output Enable
l	EN_PA	IT/VV	ļ	0: Disable PA

				1: Enable PA
				CLASS AB/D speaker function enable
0	EN ABSPK R/W (	0	0: CLASS D/K speaker function mode	
				1: CLASS AB speaker function mode

### MODE CONTROL (MODECTRL) Register (address: 0x02)

I <sup>2</sup> C Bit	Name	R/W	Default	Description	
7:5			101	Reserved and Unused	
				High power Receiver load stereo application Enabl	
4	RCV_LOAD	R/W	0	<u>0</u> : high power receiver stereo application Disable	
				1: high power receiver stereo application Enable	
				Speak & Receiver 2-in-1 application	
3	RCV_MODE	R/W	0	0: Speak & Receiver 2-in-1 application Disable	
				1: Speak & Receiver 2-in-1 application Enable	
				2-in-1 Class AB Receiver application	
2	EN_ABRCV	R/W	0	0: 2-in-1 Class D Receiver application Enable	
				1: 2-in-1 Class AB Receiver application Enable	
1:0			11	Reserved and Unused	

### CHARGEPUMP OUTPUT VOLTAGE (CPOVP) Register (address: 0x03)

I <sup>2</sup> C Bit	Name	R/W	Default	Description
7:4			0000	Reserved and Unused
				Setting Chargepump OVP Voltage
				1001~1111: Unavailable
				1000: 8.5V
				011 <mark>1: 8.25V</mark>
				<u>0110</u> : 8.0V
3:0	CP_OVP	R/W	0110	0101: 7.75V
			-	0100: 7.5V
				0011: 7.25V
				0010: 7.0V
				0001: 6.75V
				0000: 6.5V

### CHAREPUMP PARAMETER (CPP) Register (address: 0x04)

I <sup>2</sup> C Bit	Name	R/W	Default	Description
7:0			00000101	Reserved and Unused

### GAIN CONTROL (Gain) Register (address: 0x05)

For RCV\_MODE=1, RCV\_LOAD=x (Speaker & Receiver 2-in-1Mode and Receiver stereo Mode):

I <sup>2</sup> C Bit	Name	R/W	Default	Description		
7:5	<b>-</b>		000	Reserved and Unus	sed	
				Setting Class D Am	plifying Gain	
				Gain	EN_ABRCV=0	EN_ABRCV=1
				<u>00000</u> : 0dB	R <sub>ini</sub> =96kΩ	$R_{ini}=48k\Omega$
				00001: 1.5dB	$R_{ini}=80k\Omega$	$R_{ini}=48k\Omega$
				00010: 3dB	R <sub>ini</sub> =68kΩ	$R_{ini}=48k\Omega$
4:0	Gain	R/W	0000	00011: 4.5dB	R <sub>ini</sub> =56kΩ	$R_{ini}=48k\Omega$
				00100: 6.0dB	$R_{ini}=48k\Omega$	$R_{ini}=48k\Omega$
				00101: 7.5dB	R <sub>ini</sub> =60kΩ	$R_{ini}=48k\Omega$
				00110: 9.0dB	R <sub>ini</sub> =48kΩ	$R_{ini}=48k\Omega$
				00111: 10.5dB	R <sub>ini</sub> =56kΩ	R <sub>ini</sub> =48kΩ
				10011~11111: Una	vailable	

### For RCV\_MODE=0, RCV\_LOAD=0 (Speaker Mode):

I <sup>2</sup> C Bit	Name	R/W	Default	Description	
7:5			000	Reserved and Unused	
				Setting Class D Amplifying (	Gain
				Gain	
				01000: 12dB	$R_{ini}=36.5k\Omega$
				01001: 13.5dB	R <sub>ini</sub> =30kΩ
				01010: 15.0dB	$R_{ini}=25k\Omega$
				01011: 16.5dB	$R_{ini}=21.5k\Omega$
4.0	Coin	R/W	10000	01100: 18.0dB	R <sub>ini</sub> =18kΩ
4:0	Gain	FC/VV	10000	01101: 19.5dB	$R_{ini}=15.5k\Omega$
				01110: 21dB	$R_{ini}=12.5k\Omega$
				01111: 22.5dB	R <sub>ini</sub> =11kΩ
				<u>10000</u> : 24dB	$R_{ini}=9k\Omega$
				10001: 25.5dB	$R_{ini}=7.5k\Omega$
				10010: 27dB	$R_{ini}=6.5k\Omega$
				10011~11111: Unavailable	

### For RCV\_MODE=0, RCV\_LOAD=1 (Receiver stereo Mode):

7:5 000 Reserved and Unused  Setting Class D Amplifying Gain  Gain  00000: 0dB R <sub>ini</sub> =144kΩ 00001: 1.5dB R <sub>ini</sub> =120kΩ 00010: 3dB R <sub>ini</sub> =101kΩ 00011: 4.5dB R <sub>ini</sub> =86kΩ 00100: 6.0dB R <sub>ini</sub> =72kΩ 00101: 7.5dB R <sub>ini</sub> =60kΩ 00110: 9.0dB R <sub>ini</sub> =51kΩ 00110: 9.0dB R <sub>ini</sub> =42kΩ 01000: 12dB R <sub>ini</sub> =36.5kΩ 01001: 13.5dB R <sub>ini</sub> =30kΩ 01010: 15.0dB R <sub>ini</sub> =21.5kΩ 01101: 16.5dB R <sub>ini</sub> =21.5kΩ 01101: 19.5dB R <sub>ini</sub> =18kΩ 01101: 19.5dB R <sub>ini</sub> =15.5kΩ	I <sup>2</sup> C Bit	Name	R/W	Default	Description	
$eq:continuous_continuous$						
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$					Setting Class D Amplifying Gain 00000: 0dB 00001: 1.5dB 00010: 3dB 00010: 3dB 00100: 6.0dB 00101: 7.5dB 00110: 9.0dB 00111: 10.5dB 01000: 12dB 01001: 13.5dB 01001: 15.0dB 01011: 16.5dB 01101: 15.0dB 01111: 12.5dB 01101: 25.5dB 01111: 22.5dB 10000: 24dB 10001: 27dB	$\begin{array}{c} R_{ini} \!\!=\! 144 k \Omega \\ R_{ini} \!\!=\! 120 k \Omega \\ R_{ini} \!\!=\! 101 k \Omega \\ R_{ini} \!\!=\! 86 k \Omega \\ R_{ini} \!\!=\! 86 k \Omega \\ R_{ini} \!\!=\! 72 k \Omega \\ R_{ini} \!\!=\! 60 k \Omega \\ R_{ini} \!\!=\! 51 k \Omega \\ R_{ini} \!\!=\! 51 k \Omega \\ R_{ini} \!\!=\! 36.5 k \Omega \\ R_{ini} \!\!=\! 30.5 k \Omega \\ R_{ini} \!\!=\! 30.5 k \Omega \\ R_{ini} \!\!=\! 25 k \Omega \\ R_{ini} \!\!=\! 21.5 k \Omega \\ R_{ini} \!\!=\! 21.5 k \Omega \\ R_{ini} \!\!=\! 15.5 k \Omega \\ R_{ini} \!\!=\! 15.5 k \Omega \\ R_{ini} \!\!=\! 11.5 k \Omega \\ R_{ini} \!\!=\! 10.5 k \Omega \\ R_{ini} \!\!=\! 10.$

### CLASS D AGC3 OUTPUT POWER (AGC3\_Po) Register (address: 0x06) (When RCV\_LOAD=1)

I <sup>2</sup> C Bit	Name	R/W	Default	Description		
7:4			0000	Reserved and Uni	used	
				Setting AGC3 Out and stereo Receiv	•	tecting Speaker
				0000: 0.1W @8Ω	0.133W @6Ω	0.025W @32Ω
3:0	AGC3_Po	R/W	0111	0001: 0.2W @8Ω	0.267W@6Ω	0.05W@32Ω
				0010: 0.3W @8Ω	0.4W@6Ω	0.075W @32Ω
				0011: 0.4W @8Ω	0.533W @6Ω	0.1W@32Ω
				0100: 0.5W @8Ω	0.667W@6Ω	0.125W @32Ω
				0101: 0.6W @8Ω	0.8W@6Ω	0.15W@32Ω
				0110: 0.7W @8Ω	0.933W@6Ω	0.175W @32Ω
				<u>0111</u> : 0.8W @8Ω	1.067W @6Ω	0.2W@32Ω



		1000: 0.9W@8Ω	1.2W@6Ω	0.225W@32Ω
		1001: 1.0W @8Ω	1.333W @6Ω	0.25W@32Ω
		1010: 1.1W@8Ω	1.467W@6Ω	0.275W @32Ω
		1011: 1.2W @8Ω	1.6W@6Ω	0.3W@32Ω
		1100: 1.3W @8Ω	1.733W @6Ω	0.325W @32Ω
		1101: 1.4W @8Ω	1.867W @6Ω	0.35W@32Ω
		1110: 1.5W @8Ω	2.0W@6Ω	0.375W @32Ω
		1111: AGC3 Disab	ole	

### CLASS D AGC3 OUTPUT POWER (AGC3\_Po) Register (address: 0x06) (When RCV\_LOAD=0)

I <sup>2</sup> C Bit	Name	R/W	Default	Description		
7:4			0000	Reserved and Un	used	
				Setting AGC3 Out	tput Power for Pro	otecting Speaker
				0000~0011: Unav	railable	
				0100: 0.5W@8Ω	0.667W@6Ω	0.125W@32Ω
				0101: 0.6W@8Ω	0.8W@6Ω	0.15W @32Ω
				0110: 0.7W@8Ω	0.933W @ <mark>6Ω</mark>	0.175W @32Ω
				<u>0111</u> : 0.8W@8Ω	1.067W <b>@</b> 6Ω	0.2W@32Ω
3:0	AGC3 Po	R/W	0111	1000: 0.9W@8Ω	1.2W@6Ω	0.225W@32Ω
3.0	AGC3_F0	K/VV	0111	1001: 1.0W @8Ω	1. <mark>333W @6Ω</mark>	0.25W@32Ω
				1010: 1.1W@ <mark>8Ω</mark>	1.467W@6Ω	0.275W@32Ω
				1011: 1.2W@8Ω	1.6W@6Ω	0.3W@32Ω
				1100: 1.3W @8Ω	1.733W @6Ω	0.325W @32Ω
				1101: <mark>1.4W@8Ω</mark>	1.867W @6Ω	0.35W @32Ω
				11 <mark>10: 1.5W@8</mark> Ω	2.0W@6Ω	0.375W @32Ω
				1111: AGC3 Disa	ble	

### CLASS D AGC3 PARAMETER (AGC3) Register (address: 0x07)

I <sup>2</sup> C Bit	Name	R/W	Default	Description
				Setting Release Time of AGC3:
				000: 5.12ms/dB
				001: 10.24ms/dB
				<u>010</u> : 21 ms/dB
7:5	AGC3_RT	R/W	010	011: 41 ms/dB
				100: 82 ms/dB
				101: 164 ms/dB
				110: 328 ms/dB
				111: Unavailable
				Setting Attack Time of AGC3:
				000: 0.64ms/dB
				001: 1.28ms/dB
	AGC3_AT	R/W	100	010: 2.56ms/dB
4:2				011: 10.24ms/dB
				100: 41ms/dB
				101: 82ms/dB
				110: 164ms/dB
				111: 328ms/dB
1:0			10	Reserved and Unused

### CLASS D AGC2 OUTPUT POWER(AGC2\_Po) Register (address: 0x08)

I <sup>2</sup> C Bit	Name	R/W	Default	Description				
7:4			0000	Reserved and Unused				
	AGC2_Po	R/W	0110	Setting AGC2 Output Power:				
3:0				0000: 0.4W@8Ω   0.533W@6Ω   0.1W@32Ω				
0.0				0001: 0.6W@8Ω   0.8W@6Ω   0.15W@32Ω				
				0010: 0.8W@8Ω   1.067W@6Ω   0.2W@32Ω				

	0011: 1.0W@8Ω	1.333W @6Ω	0.25W@32Ω
	0100: 1.2W@8Ω	1.6W@6Ω	0.25V @ 32Ω 0.3W @ 32Ω
	0100: 1.2W @ 8Ω 0101: 1.4W @ 8Ω	1.867W @6Ω	0.35W @32Ω
	0110: 1.6W@8Ω	2.133W @6Ω	0.4W@32Ω
	0111: 1.8W@8Ω	2.4W@6Ω	0.45W@32Ω
	1000: 2.0W@8Ω	2.667W @6Ω	0.5W@32Ω
	1001: AGC2		<u> </u>
	Disable		
	1010~1111: Unav	ailable	

### CLASS D AGC2 PARAMETER (AGC2) Register (address: 0x09)

I <sup>2</sup> C Bit	Name	R/W	Default	Description
7:5			00	
				Setting Attack Time of AGC2:
				000: 0.16ms/dB
				001: 0.32ms/ dB
				010: 0.64ms/dB
4:2	AGC2_AT	R/W	010	011: 2.56ms/dB
				100: 10.24ms/dB
				101: 41ms/dB
				110: 82ms/dB
				111: 164ms/dB
1:0			00	Reserved and Unused

### CLASS D AGC1 PARAMETER (AGC1) Register (address: 0x0A)

I <sup>2</sup> C Bit	Name	R/W	Default	Default Description				
7:4			1001 Reserved and Unused					
				Setting Fastest Level AGC Attack Time:				
				00: 0.04ms/dB				
3:2	AGC1_AT	R/W	01	01: 0.08ms/dB				
				10: 0.16ms/dB				
				11: 0.32ms/dB				
1			1	Reserved and Unused				
				AGC1 control bit				
0	PD_ AGC1	R/W	0	0: AGC1 Enable				
				1: AGC1 Disable				



### **APPLICATION INFORMATION**

### **Capacitor Selection**

The output capacitor of chargepump is usually within the range  $0.1\mu\text{F}\sim47\mu\text{F}$ , It needs to use Class II type (EIA) multilayer ceramic capacitors (MLCC). Its internal dielectric is ferroelectric material (typically BaTiO3), a high the dielectric constant in order to achieve smaller size, but at the same Class II type (EIA) multilayer ceramic capacitors has poor temperature stability and voltage stability as compared to the Class I type (EIA) capacitance. Capacitor is selected based on the requirements of temperature stability and voltage stability, considering the capacitance material, capacitor voltage, and capacitor size and capacitance values.

### a) temperature stability

Class II capacitance have different temperature stability in different materials, usually choose X5R type in order to ensure enough temperature stability, and X7R type capacitance has better properties, the price is relatively more expensive. X5R capacitance change within ±15% in temperature range of 55°C to 85°C, X7R capacitance change within ±15% in temperature range of -55°C~125°C. The output capacitance of the AW87349's chargepump recommends X5R ceramic capacitors.

### b) Voltage Stability

Class II type capacitor has poor voltage stability ——Capacitance values falling fast along with the DC bias voltage applied across the capacitor increasing. The rate of decline is related to capacitance material, capacitors rated voltage, capacitance volume. Take for TDK C series X5R for example, its pressure voltage value is 16V or 25V, the package size is 0805, 1206 or 0603, the capacitance value is 10µF. The capacitor's voltage stability of different types of capacitor is as shown below:

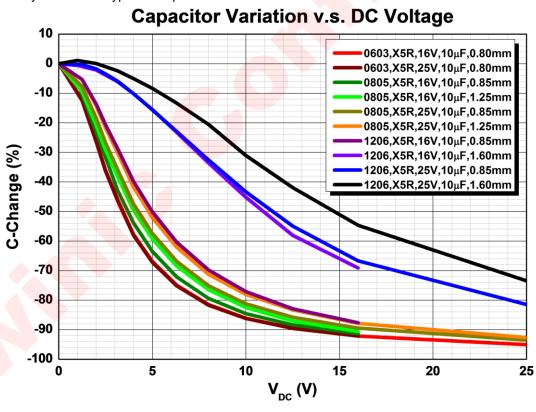


Figure 24 Different Types of Capacitive Voltage Stability

Among them, the space remaining value of different types of capacitors at VDC = 8.5V as shown below:

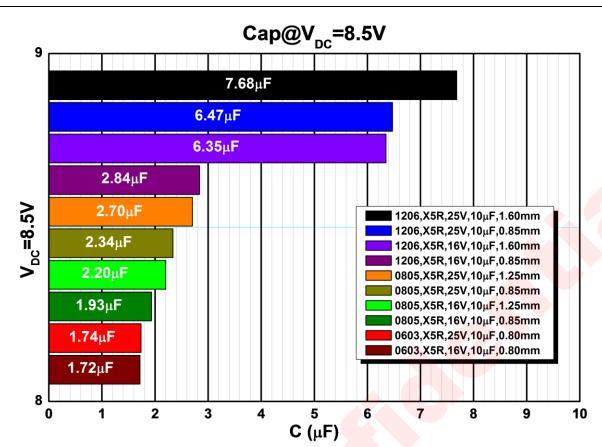


Figure 25 The Space Remaining Value of Different Types of Capacitors at V<sub>DC</sub> = 8.5V

It can be found that the rate of capacitance capacity value descent becomes slow along with "large capacitor size, capacitance pressure voltage rise". The larger the package size, the better voltage stability the higher the height, the better voltage stability with the same length and width of the capacitance. Voltage stability of smaller package size (0603) capacitor change affected by the pressure value is very small.

In AW87349 typical applications, it is necessary to ensure the output value of the PVDD capacitor ≥3µF when PVDD=8.5V.

### Input Capacitor-C<sub>in</sub> (input high-pass cutoff frequency)

The input capacitors and input resistors form a high-pass filter to filter out the DC component of the input signal. The -3dB frequency points of the high pass filter is shown below:

$$f_{H}(-3dB) = \frac{1}{2*\pi*R_{intotal}*C_{in}}(Hz)$$

The selection of a smaller Cin capacitor in the application helps to filter out 217Hz noise, which comes from the input coupling, and the smaller capacitor is advantageous to reduce the pop-click noise when the power amplifier turn on.Better matching of the input capacitors improves performance of the circuit and also helps to suppress pop-click noise. A capacitor value deviation of 10% or better capacitance is recommended.

Take typical application as an example, the input high-pass cutoff frequency is calculated as below:

$$f_{H}(-3dB) = \frac{1}{2*\pi*R_{intotal}*C_{in}} = \frac{1}{2*\pi*9k\Omega*100nF}(Hz) = 177Hz$$

Class D-type speaker & receiver 2-in-1 application (Gain=1), the input high pass frequency is as follows:



$$f_{H}(-3dB) = \frac{1}{2*\pi*R_{intotal}*C_{in}} = \frac{1}{2*\pi*96k\Omega*100nF}(Hz) = 16.5Hz$$

Class AB-type speaker & receiver 2-in-1 (Gain=1), the input high pass frequency is as follows:

$$f_{H}(-3dB) = \frac{1}{2*\pi*R_{intotal}*C_{in}} = \frac{1}{2*\pi*48k\Omega*100nF}(Hz) = 33Hz$$

### Supply Decoupling Capacitor (C<sub>S</sub>)

A good decoupling capacitor can improve the efficiency and the best performance of the power amplifier. At the same time, in order to get good high frequency transient performance, the ESR value of the capacitor should be as small as possible. In AW87349 applications, low ESR (equivalent-series-resistance) X7R or X5R ceramic capacitors are recommended. Generally, 10µF ceramic capacitors are used to bypass the VDD to the ground, and the decoupling capacitor should be placed as close to the VDD chip as possible in the layout. If you want to filter out low-frequency noise better, you need to add a 10µF or greater decoupling capacitor depending on your application. Meanwhile, a 33pF~0.1µF ceramic capacitor is placed on the pin of the power supply to filter the high frequency interference on the power supply. The capacitor should be placed as close as possible to the D4 pin and inductor.

### Chargepump Flying capacitor (C<sub>F</sub>)

The Flying capacitor is used to transfer energy between the power supply and the chargepump load, the value of the Flying capacitor directly affects the load regulation rate and the output drive capability of the chargepump. If flying capacitor is too small, it will affect the chargepump load adjustment rate and output drive capability, thereby affecting the power output of the amplifier, and the larger the Flying capacitor, the better the load regulation ability, driving ability is also stronger. Recommended use of 4.7µF, low ESR X7R, X5R ceramic capacitors, it is recommended to use more than 10V pressure capacitor.

### Output capacitance of chargepump (C<sub>OUT</sub>)

The output capacitance of the chargepump and the ESR directly affect the ripple of the output, thus affecting the performance of the power amplifier. Recommended use of 10µF, low ESR X7R or X5R ceramic capacitors, you need to select the 25V voltage resistance capacitor.

### Output beads, capacitors, TVS

Using EEE technology, in the class K mode, the AW87349 can also meet the FCC CLASS B specification requirements. It is recommended to Use ferrite chip beads and capacitors if device near the EMI sensitive circuits, there are long leads from amplifier to speaker, placed as close as possible to the output pin.



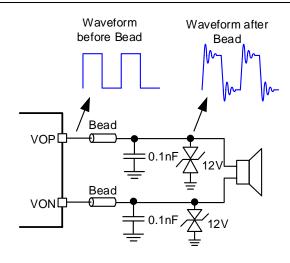


Figure 26 Ferrite Chip Bead and Capacitor

Amplifier output is a square wave signal. The voltage across the capacitor will be much larger than the PVDD voltage after increasing the bead capacitor. It suggested the use of rated voltage above 16V capacitor. At the same time a square wave signal at the output capacitor switching current form, the static power consumption increases, so the output capacitance should not be too much which is recommended 0.1nF ceramic capacitor rated voltage of 16V. If you want to get better EMI suppression performance, can use 1nF, rated voltage 16V capacitor, but quiescent current will increase.

Power amplifier output PWM signals of high voltage to PVDD voltage, voltage to 8.5 V, will produce some ringing after bead capacitor, resulting in higher peak voltage. Recommended choose the operating voltage of 12V TVS.

### PCB AND DEVICE LAYOUT CONSIDERATION

### EXTERNAL COMPONENTS PLACEMENT

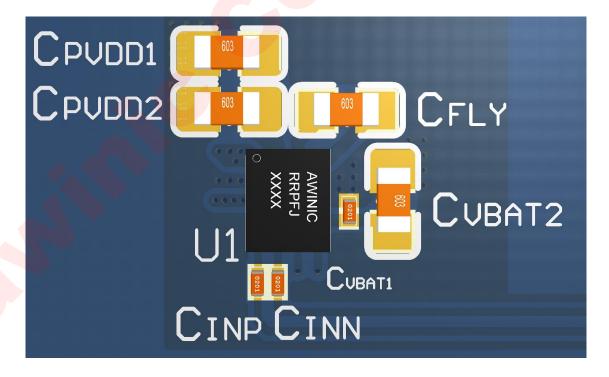


Figure 27 AW87349 External Components Placement

### LAYOUT CONSIDERATIONS

This device is a power a power amplifier chip. To obtain the optimal performance, PCB layout should be considered carefully. The suggested Layout is illustrated in the following diagram:

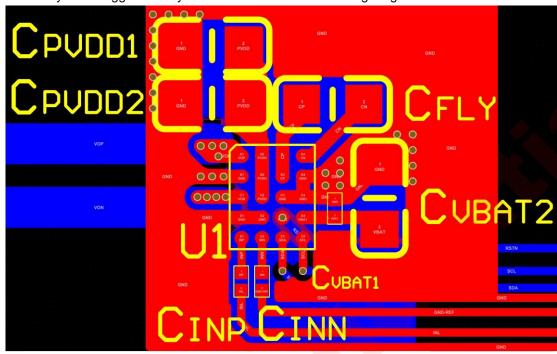


Figure 28 AW87349 Board Layout

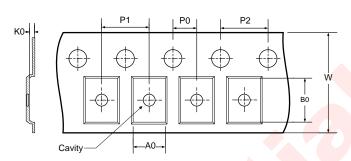
In order to obtain excellent performance of AW87349, PCB layout must be carefully considered. The design consideration should follow the following principles:

- 1. In AW87349 peripheral device layout, you first need to guarantee the chargepump output capacitance close to PVDD pin.
- 2. Try to provide a separate short and thick power line to AW87349, the copper width is recommended to be larger than 0.75mm. The decoupling capacitors should be placed as close as possible to boost power supply pin.
- 3. The input capacitors should be close to AW87349 INN and INP input pin, the input line should be parallel to suppress noise coupling.
- 4. The beads and capacitor should be placed near to AW87349 VON and VOP pin. The output line from AW87349 to speaker should be as short and thick as possible. The width is recommended to be larger than 0.5mm.

### **TAPE & REEL DESCRIPTION**

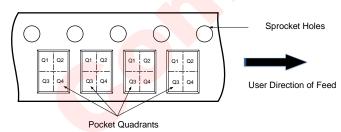
# REEL DIMENSIONS D1

### TAPE DIMENSIONS



- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- K0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P0: Pitch between successive cavity centers and sprocket hole
- P1: Pitch between successive cavity centers
- P2: Pitch between sprocket hole
- D0: Reel width
- D1: Reel diameter

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

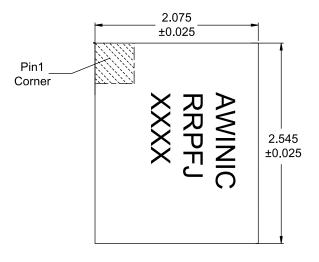


### All dimensions are nominal

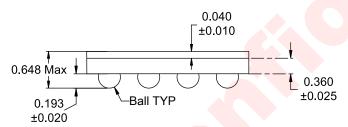
D1 (mm)	D0 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
330.00	12.40	2.20	2.67	0.83	2.00	8.00	4.00	12.00	Q1



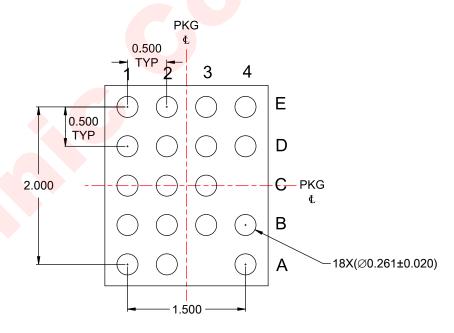
### **PACKAGE DESCRIPTION**



Top View



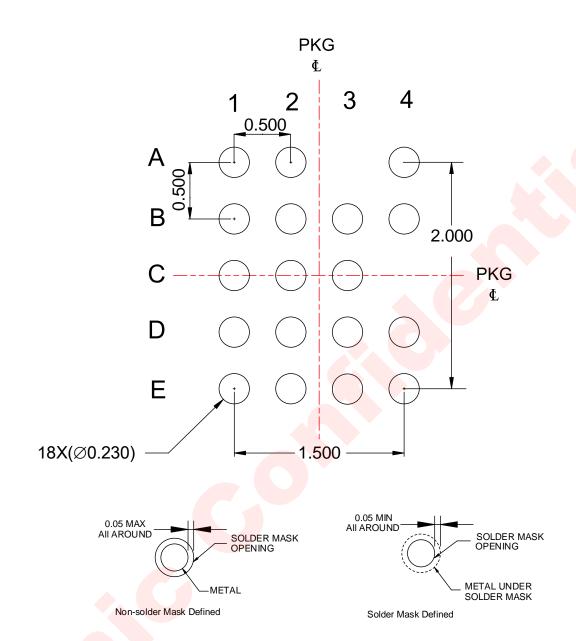
Side View



**Bottom View** 

Dimensions are all in millimeters

### **LAND PATTERN DATA**



Dimensions are all in millimeters

### **VERSION INFORMATION**

Version	Date	Description
V1.0	2018-06-18	AW87349CSR datasheet V1.0



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